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July 2016

FFSP3065A

Silicon Carbide Schottky Diode

650 V, 30 A

Features

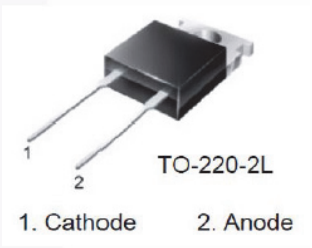
- Max Junction Temperature 175 °C
- Avalanche Rated 180 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery

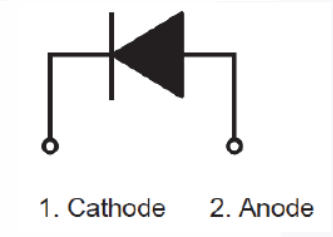
Description

SiC Schottky Diode has no switching loss, provides improved system efficiency against Si diodes by utilizing new semiconductor material - Silicon Carbide, enables higher operating frequency, and helps increasing power density and reduction of system size/cost. Its high reliability ensures robust operation during surge or over-voltage conditions

Applications

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits





Absolute Maximum Ratings T_C = 25 °C unless otherwise noted.

Symbol	Parameter		FFSP3065A	Unit
V_{RRM}	Peak Repetitive Reverse Voltage		650	V
E_{AS}	Single Pulse Avalanche Energy (Note 1)		180	mJ
I_F	Continuous Rectified Forward Current @ T_C < 148 °C		30	A
$I_{F, Max}$	Non-Repetitive Peak Forward Surge Current	T_C = 25 °C, 10 µs	1125	A
		T_C = 150 °C, 10 µs	1040	A
$I_{F,SM}$	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t_p = 8.3 ms	150	A
$I_{F,RM}$	Repetitive Forward Surge Current	Half-Sine Pulse, t_p = 8.3 ms	75	A
Ptot	Power Dissipation	T_C = 25 °C	240	W
		T_C = 150 °C	40	W
T_J, T_{STG}	Operating and Storage Temperature Range		-55 to +175	°C

Thermal Characteristics

Symbol	Parameter	FFSP3065A	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.62	°C/W

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Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSP3065A	FFSP3065A	TO-220-2L	Tube	N/A	N/A	50 units

Electrical Characteristics T_C = 25 °C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_F	Forward Voltage	I_F = 30 A, T_C = 25 °C	-	1.50	1.75	V
		I_F = 30 A, T_C = 125 °C	-	1.60	2.0	
		I_F = 30 A, T_C = 175 °C	-	1.72	2.4	
I_R	Reverse Current	VR = 650 V, T_C = 25 °C	-	-	200	μA
		VR = 650 V, T_C = 125 °C	-	-	400	
		VR = 650 V, T_C = 175 °C	-	-	600	
Q_C	Total Capacitive Charge	V = 400 V	-	100	-	nC
C	Total Capacitance	V_R = 1 V, f = 100 kHz	-	1705	-	pF
		V_R = 200 V, f = 100 kHz	-	180	-	
		V_R = 400 V, f = 100 kHz	-	130	-	

Notes:
1: EAS of 180 mJ is based on starting T_J = 25 °C, L = 0.5 mH, I_{AS} = 27 A, V = 50 V.

Typical Characteristics T_J = 25 °C unless otherwise noted.

Figure 1. Forward Characteristics

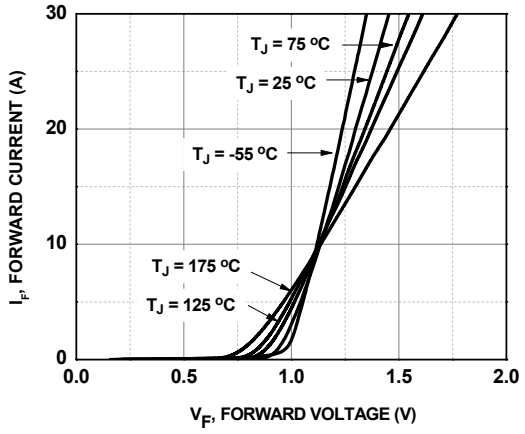


Figure 2. Reverse Characteristics

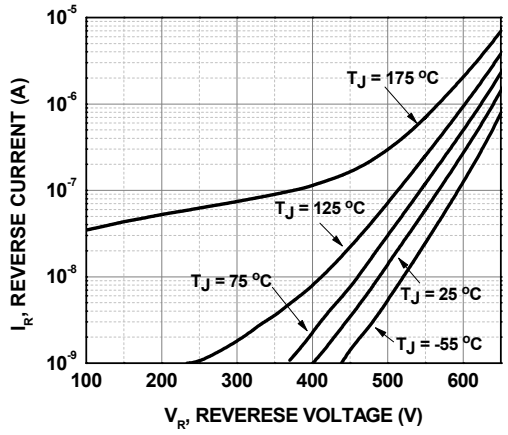


Figure 3. Current Derating

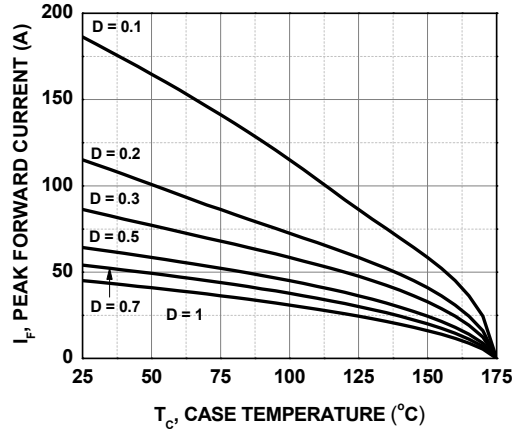
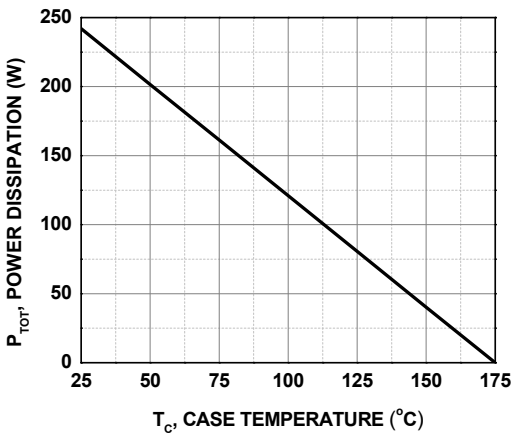


Figure 4. Power Derating



Typical Characteristics T_J = 25 °C unless otherwise noted.

Figure 5. Capacitive Charge vs. Reverse Voltage

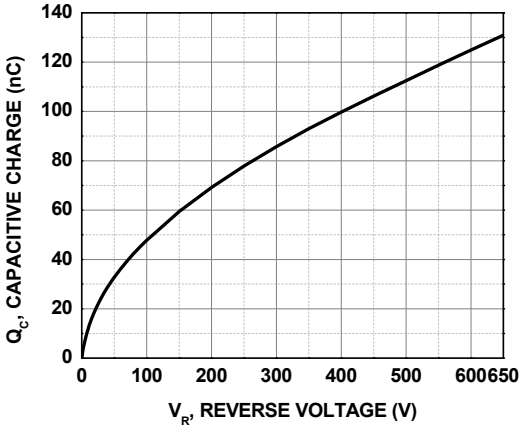


Figure 6. Capacitance vs. Reverse Voltage

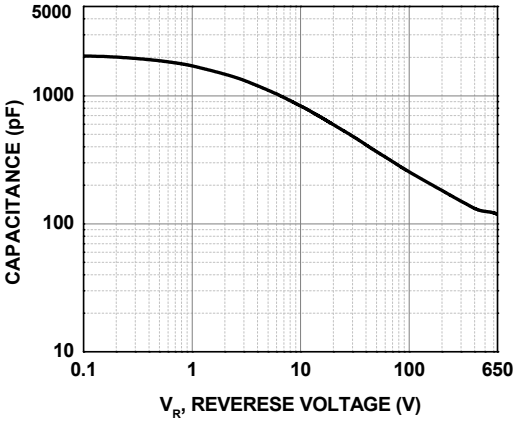


Figure 7. Capacitance Stored Energy

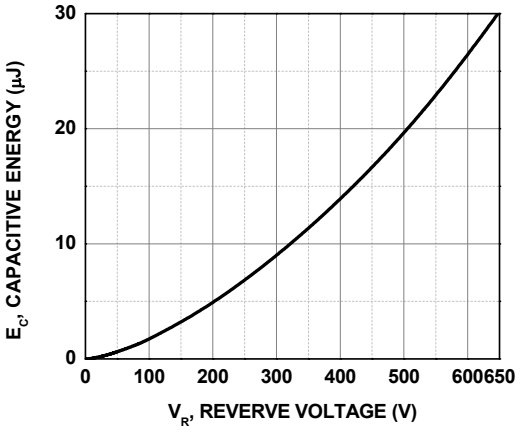
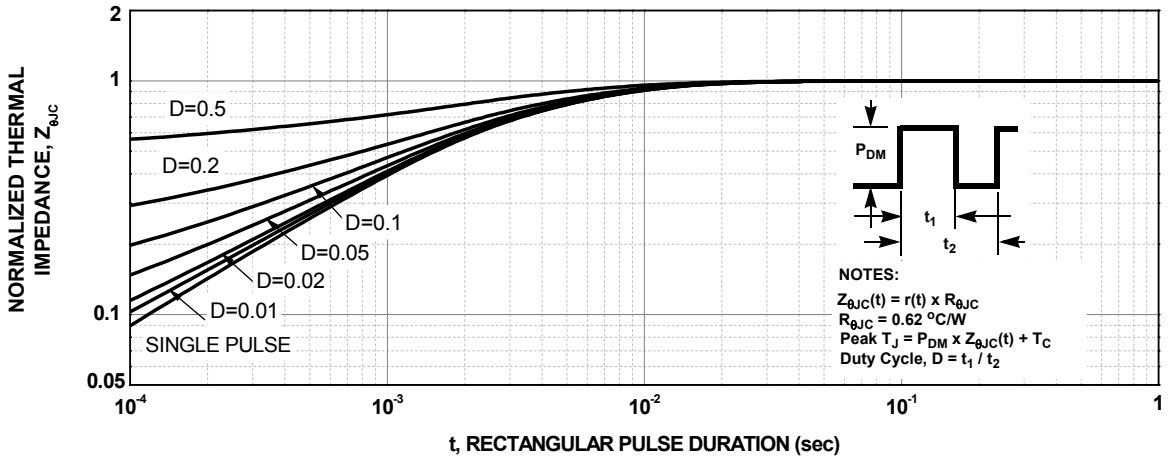
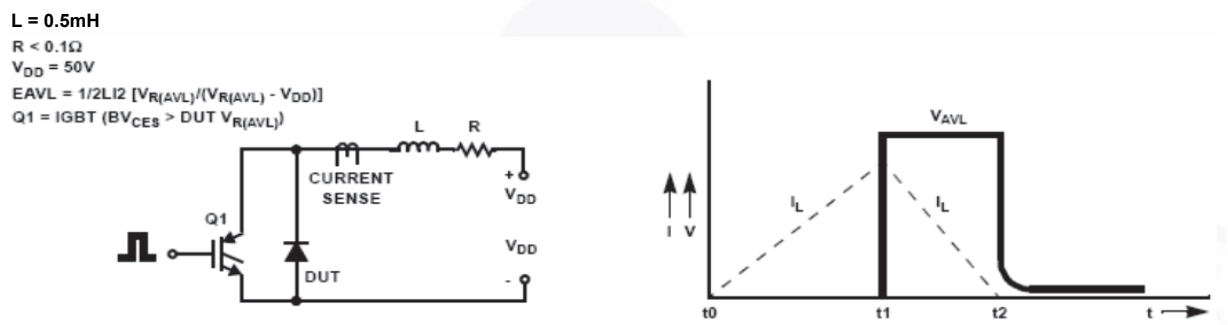


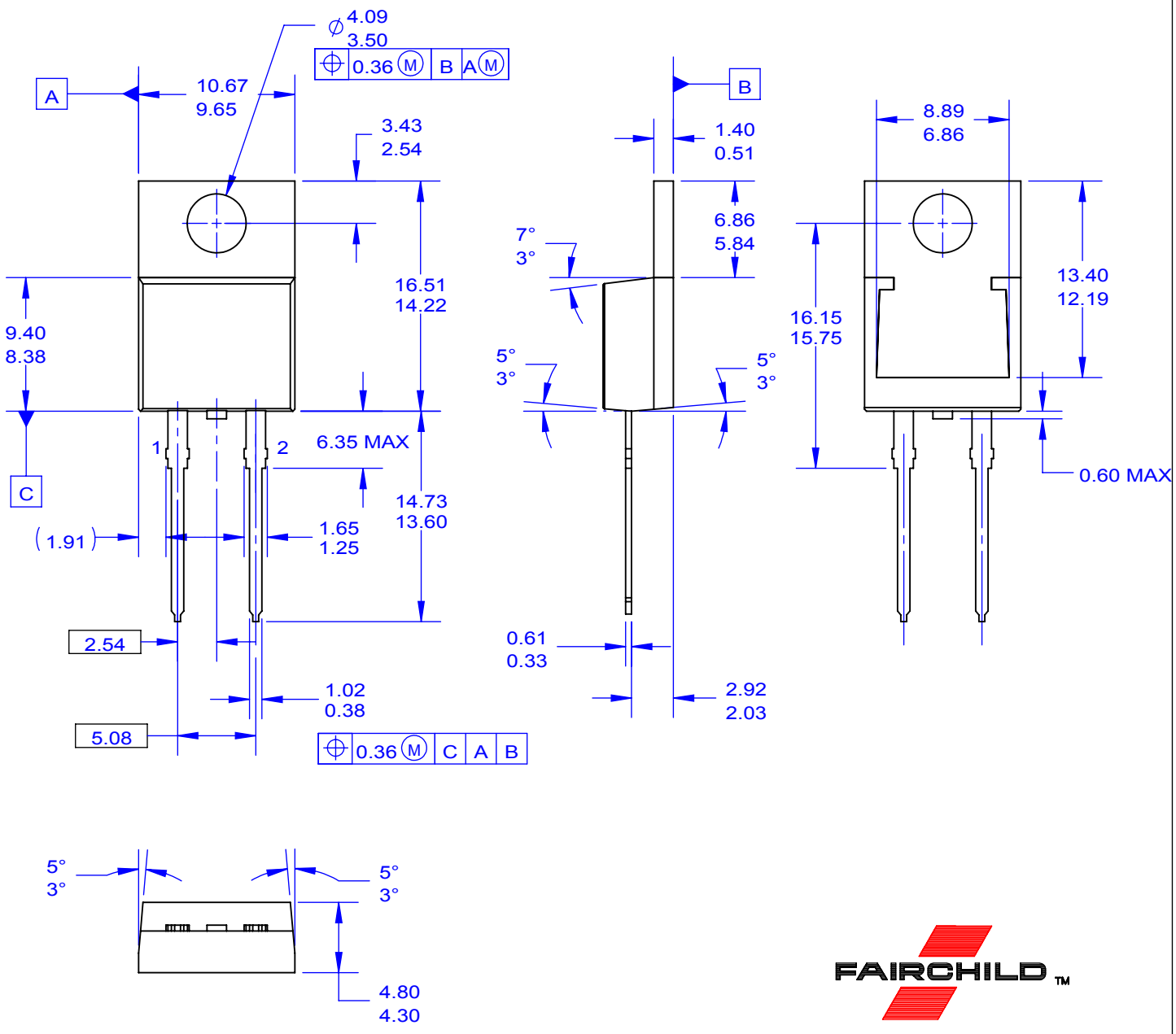
Figure 8. Junction-to-Case Transient Thermal Response Curve



Test Circuit and Waveforms

Figure 9. Unclamped Inductive Switching Test Circuit & Waveform





NOTES:

A. PACKAGE REFERENCE: JEDEC TO220,ISSUE K, VARIATION AC,DATED APRIL 2002.
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C. DIMENSION AND TOLERANCE AS PER ASME Y14.5-2009.
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